

# RJK0629DPE

60V, 85A, 4.5m max. N Channel Power MOS FET High-Speed Switching Use

R07DS1060EJ0200

(Previous: REJ03G1874-0100)

Rev.2.00

Apr 09, 2013

#### **Features**

• V<sub>DSS</sub>: 60 V

•  $R_{DS(on)}$ : 4.5 m $\Omega$  (Max)

• I<sub>D</sub>: 85 A

### **Outline**

RENESAS Package code: PRSS0004AE-B (Package name: LDPAK(S)-(1) )

2, 4

1 Gate
2. Drain
3. Source
4. Drain

### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Value	Unit
Drain to source voltage	V <sub>DSS</sub>	60	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	I <sub>D</sub>	85	А
Drain peak current	I <sub>D</sub> (pulse) Note1	340	А
Body-drain diode reverse drain current	I <sub>DR</sub>	85	А
Body-drain diode reverse drain peak current	I <sub>DR</sub> (pulse) Note1	340	А
Avalanche current	I <sub>AP</sub> Note2	55	А
Channel dissipation	Pch Note3	100	W
Channel to case thermal impedance	θch-c	1.25	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Tc = 25°C, Tch  $\leq$  150°C, L = 100  $\mu H$ 

3. Value at Tc = 25°C

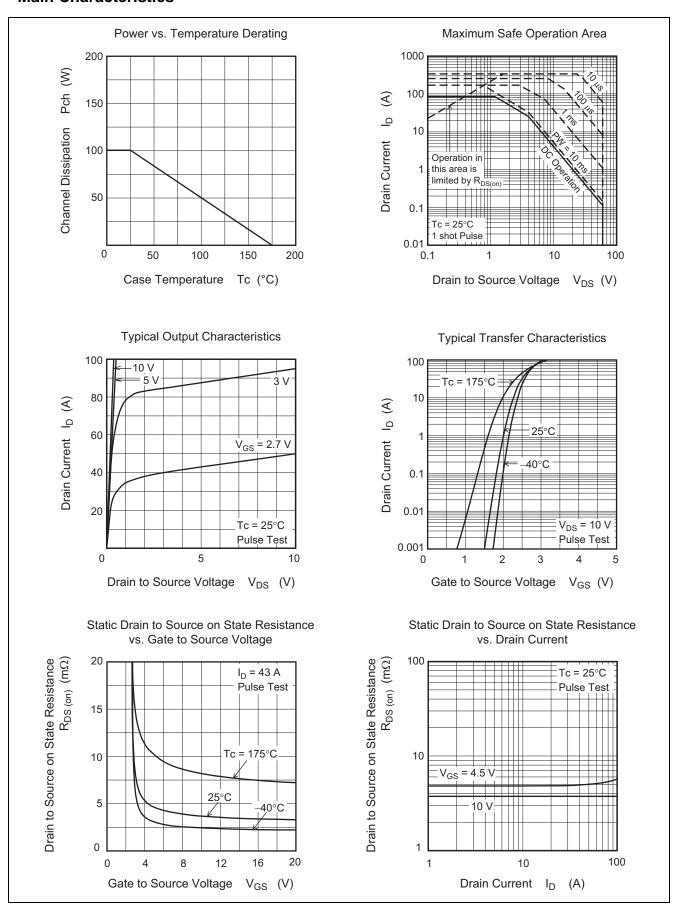
## **Electrical Characteristics**

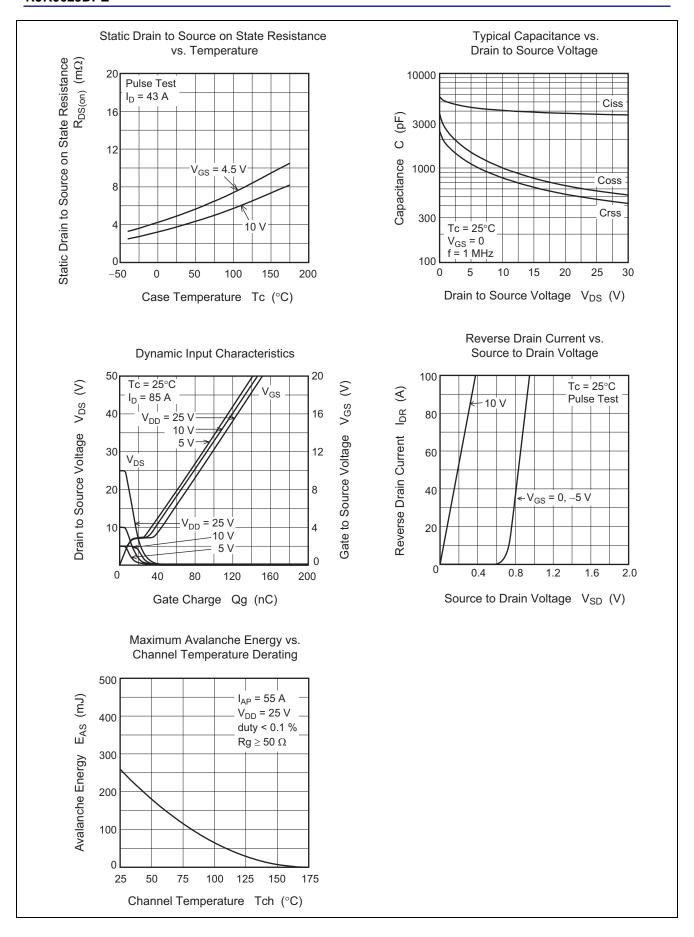
 $(Ta = 25^{\circ}C)$ 

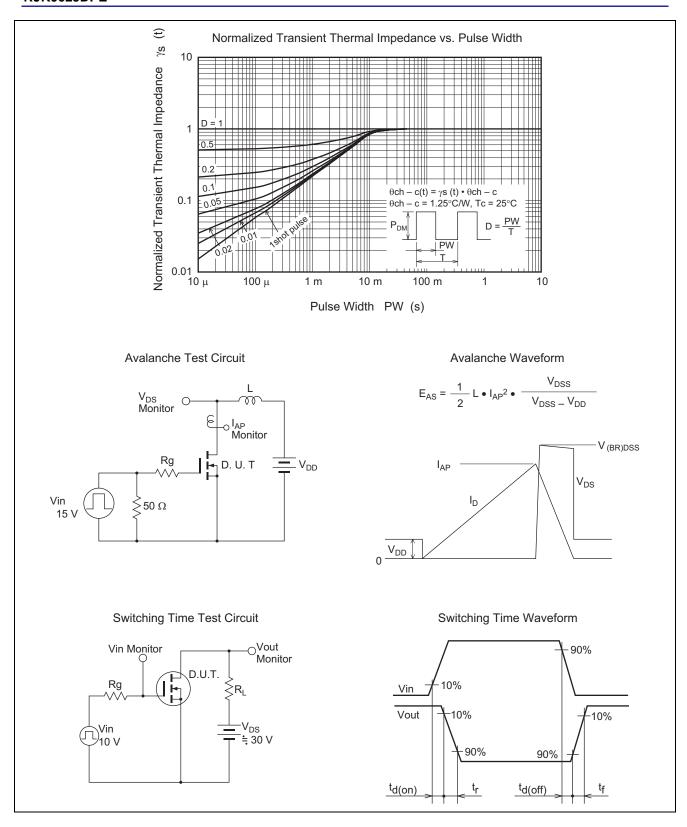
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	60	_	_	V	$I_D = 100 \ \mu A, \ V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>		_	1	μΑ	$V_{DS} = 60 \text{ V}, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	_	2.0	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state voltage	V <sub>DS(on)</sub>	_	161	194	mV	$I_D = 43A$ , $V_{GS} = 10 \text{ V}^{\text{Note}4}$
Static drain to source on state	R <sub>DS(on)</sub>	_	3.75	4.5	mΩ	$I_D = 43A$ , $V_{GS} = 10 \text{ V}^{\text{Note}4}$
resistance		_	4.9	6.6	mΩ	$I_D = 43 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note}4}$
Input capacitance	Ciss	_	4100	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0$
Output capacitance	Coss	_	1000	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	780	_	pF	
Total gate charge	Qg	_	85	_	nC	$V_{DD} = 25 \text{ V}, V_{GS} = 10 \text{ V},$
Gate to source charge	Qgs	_	11	_	nC	$I_D = 85 A$
Gate to drain charge	Qgd	_	25	_	nC	
Turn-on delay time	t <sub>d(on)</sub>	_	20	_	ns	$V_{DD} = 30V, I_{D} = 43A,$
Rise time	t <sub>r</sub>	_	40	_	ns	$V_{GS} = 10 \text{ V}, R_{G} = 4.7 \Omega$
Turn-off delay time	t <sub>d(off)</sub>	_	100	_	ns	
Fall time	t <sub>f</sub>	_	40	_	ns	1
Body-drain diode forward voltage	$V_{DF}$	_	0.92	1.2	V	$I_F = 85 \text{ A}, V_{GS} = 0^{\text{Note}4}$
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	50	_	ns	$I_F = 85 \text{ A}, V_{GS} = 0,$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

Note: 4. Pulse test

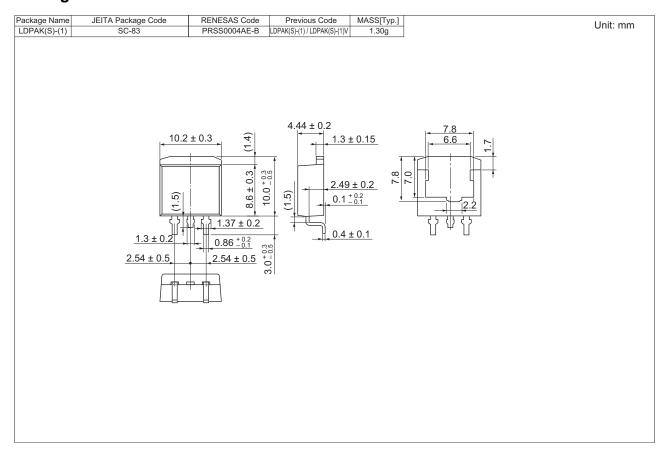
### **Main Characteristics**







## **Package Dimensions**



## **Ordering Information**

Part No.	Quantity	Shipping Container
RJK0629DPE-00-J3	1000 pcs	Taping

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Renesas Electronics Canada Limited 1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Milliboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd. 7th Floor, Quantum Plaza, No.27 ZhiChunLu Ha Tel: +86-10-8235-1155, Fax: +86-10-8235-7679 i. nunLu Haidian District. Beiiing 100083. P.R.China

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2868-9318, Fax: +852 2869-9022/9044

Renesas Electronics Taiwan Co., Ltd. 13F, No. 363, Fu Shing North Road, Taipei, Taiwan Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

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Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

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